

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	190	scr near (trigger triggering) same (mos mosfet fet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/18 15:07
S2	5	pnpn near (trigger triggering) same (mos mosfet fet)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 13:44
S3	10	scr near (trigger triggering) same (mos mosfet fet transistor) near series	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 13:53
S4	4960	esd near (protect protecting protection)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 13:53
S5	695	esd near (protect protecting protection) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 13:54
S6	2	esd near (protect protecting protection) and scr and rc near (trigger triggering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 14:02
S7	2	("5602404" "5872379").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/17 13:58
S8	25	("5602404").URPN.	USPAT	OR	ON	2005/02/17 13:59
S9	695	esd near (protect protecting protection) and scr	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 14:02
S10	17	esd near (protect protecting protection) and scr and transistor near (serial series)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 14:30
S11	555	esd near (protect protecting protection) and RC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 14:30

S12	24	esd near (protect protecting protection) and RC near (trigger triggering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 14:39
S13	23	"5,946,177"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 16:36
S14	6	("5239440" "5287241" "5440162" "5559659" "5654862" "5745323").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/17 14:39
S15	886	361/91.1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/17 16:36
S16	0	(zeev near kitov or z near kitov) and adrey	US-PGPUB; USPAT	OR	ON	2005/02/18 09:54
S17	504	esd same scr	US-PGPUB; USPAT	OR	ON	2005/02/18 09:54
S18	0	esd same scr and adrey	US-PGPUB; USPAT	OR	ON	2005/02/18 09:54
S19	358	esd same scr same (trigger triggering)	US-PGPUB; USPAT	OR	ON	2005/02/18 09:55
S20	100	esd same scr and zener near diode	US-PGPUB; USPAT	OR	ON	2005/02/18 09:55
S21	71	esd same scr and scr same zener near diode	US-PGPUB; USPAT	OR	ON	2005/02/18 09:55
S22	13	("4130767" "4567500" "5072273" "5274262" "5343053" "5400202" "5572394" "5615074" "5663860" "5932916" "5959332" "5986307" "6016002").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/18 09:58
S23	13	("4130767" "4567500" "5072273" "5274262" "5343053" "5400202" "5572394" "5615074" "5663860" "5932916" "5959332" "5986307" "6016002").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/18 11:06
S24	9	("3886432" "4066918" "4323942" "4405933" "4484244" "5010380" "5072273" "5274262" "5343053").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/18 11:22

S25	8	"3,886,432"	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/18 12:16
S26	1463	(MOS MOSFET FET field adj effect) near (protect protecting protected)	US-PGPUB; USPAT; USOCR	OR	ON	2005/02/18 12:17
S27	999	(MOS MOSFET FET field adj effect) near (protect protecting protected)	US-PGPUB; USPAT	OR	ON	2005/02/18 12:19
S28	361	(MOS MOSFET FET field adj effect) near (protect protecting protected) and zener near diode	US-PGPUB; USPAT	OR	ON	2005/02/18 12:19
S29	361	(MOS MOSFET FET field adj effect) near (protect protecting protected) and zener adj diode	US-PGPUB; USPAT	OR	ON	2005/02/18 12:19
S30	253	(MOS MOSFET FET field adj effect) near (protect protecting protected) and zener adj diode same gate	US-PGPUB; USPAT	OR	ON	2005/02/18 12:20
S31	253	(MOS MOSFET FET field adj effect) near (protect protecting protected) and zener adj diode near diode same gate	US-PGPUB; USPAT	OR	ON	2005/02/18 12:20
S32	137	(MOS MOSFET FET field adj effect) near (protect protecting protected) and zener adj diode near diode same gate same drain	US-PGPUB; USPAT	OR	ON	2005/02/18 12:45
S33	4259	361/56	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/18 13:31
S34	1073	361/91.5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/02/18 15:08